LMV321/LMV358/LMV324

GENERAL PURPOSE, LOW VOLTAGE, RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

Description

The LMV321/LMV358/LMV324 are low voltage (2.7V to 5.5V) single, dual and quad operational amplifiers. The LMV321/LMV358/LMV324 are designed to effectively reduce cost and space at low voltage levels.

These devices have the capability of rail-to-rail output swing and input common-mode voltage range includes ground. They can also achieve an efficient speed-to-power ratio, utilizing 1 MHz bandwidth and 1 V/µs slew rate at a low supply current. Reducing noise pickup and increasing signal integrity can be achieved by placing the device close to the signal source.

The LMV321 is available in 5-Pin SOT353/SOT25 packages that reduce space on PC boards and portable electronic devices. The LMV324 is available in the SOP-14L and TSSOP-14L package.

The LMV358 is available in the MSOP-8L and SOP-8L packages.

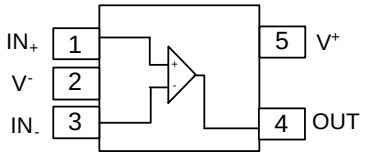
Features

(For V^+=5V and V^-=0V typical unless otherwise noted)

- Guaranteed 2.7V and 5V performance
- Crossover distortion eliminated
- Operating temperature range (-40℃ to +85℃)
- Gain-bandwidth product 1 MHz
- Low supply current
  - LMV321 110 µA Typ
  - LMV358 190 µA Typ
  - LMV324 340 µA Typ
- Rail-to-rail output swing @ 10 kΩ
  - V^+ -10 mV
  - V^- +10 mV
- Input Common Mode Voltage Range (-0.2 to V^+ -0.8V)
- Manufactured in standard CMOS process
- SOT353, SOT25, MSOP-8L, SOP-8L, SOP-14L & TSSOP-14L: Available in “Green” Molding Compound (No Br, Sb)
- Lead-free Finish/ RoHS Compliant (Note 1)

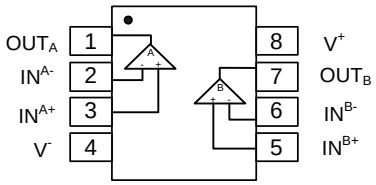
Pin Assignments

(Top View)



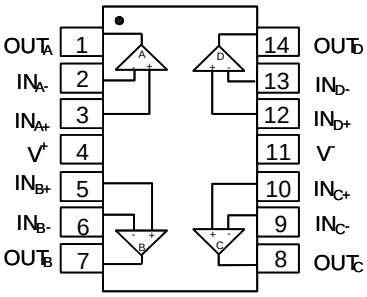
SOT25 / SOT353

(Top View)



SOP-8L / MSOP-8L

(Top View)



SOP-14L / TSSOP-14L

Application

- Active filters
- General purpose low voltage applications
- General purpose portable devices

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html

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Absolute Maximum Ratings (Note 2)

Symbol	Description		Rating	Unit
ESD HBM	Human Body Model ESD Protection	LMV321	4.0	KV
		LMV358	4.0	
		LMV324	4.5	
ESD MM	Machine Model ESD Protection	LMV321	350	V
		LMV358	350	
		LMV324	250	
	Differential Input Voltage		±Supply Voltage	V
V^+ -V^-	Supply Voltage		5.5	V
	Output Short Circuit to V^+		(Note 3)	
	Output Short Circuit to V^-		(Note 4)	
T_{ST}	Storage Temperature		-65 to 150	℃
T_J	Maximum Junction Temperature		150	℃

Notes:
2. Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.
3. Shorting output to V+ will adversely affect reliability.
4. Shorting output to V- will adversely affect reliability.

Recommended Operating Conditions

Symbol	Description	Rating	Unit
V^+ -V^-	Supply Voltage	2.7 to 5.5	V
T_A	Operating Ambient Temperature Range	-40 to +85	℃

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Electrical Characteristics

2.7V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_A = 25℃, V^+ = 2.7V, V^- = 0V, V_{CM} = 1.0V, V_O = V^+/2 and R_L > 1 MΩ.

Symbol	Parameter	Test Conditions	Min (Note 6)	Typ. (Note 5)	Max (Note 6)	Unit
V_{OS}	Input Offset Voltage			1.7	7	mV
TCV_{OS}	Input Offset Voltage Average Drift			5		μV/℃
I_B	Input Bias Current			10		nA
I_{OS}	Input Offset Current			5	50	nA
CMRR	Common Mode Rejection Ratio	0V ≤ V_{CM} ≤ 1.7V	50	63		dB
PSRR	Power Supply Rejection Ratio	2.7V ≤ V^+ ≤ 5V V_O = 1V	50	60		dB
V_{CMR}	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	0	-0.2		V
				1.9	1.7	
V_O	Output Swing	R_L = 10 kΩ to 1.35V	V^+ - 100	V^+ - 20		mV
				20	100	
I_S	Supply Current	LMV321 Single amplifier		110	140	μA
		LMV358 Both amplifiers		190	340	μA
		LMV324 All four amplifiers		340	680	μA

2.7V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_A = 25℃, V^+ = 2.7V, V^- = 0V, V_{CM} = 1.0V, V_O = V^+/2 and R_L > 1 MΩ.

GBWP	Gain-Bandwidth Product	C_L = 200 pF		1		MHz
Φm	Phase Margin			60		Deg
Gm	Gain Margin			10		dB
e_n	Input-Referred Voltage Noise	f > 50 kHz		23		$\frac{nV}{\sqrt{Hz}}$

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Electrical Characteristics (Continued)

5V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_A = 25℃, V^+ = 5V, V^- = 0V, V_{CM} = 2.0V, V_O = V^+/2 and R_L > 1 MΩ.

Symbol	Parameter	Test Conditions			Min (Note 6)	Typ. (Note 5)	Max (Note 6)	Unit
V_{OS}	Input Offset Voltage	T_A = 25℃				1.7	7	mV
		T_A = full range					9	
TCV_{OS}	Input Offset Voltage Average Drift					5		μV/℃
I_B	Input Bias Current	T_A = 25℃				15	250	nA
		T_A = full range					500	
I_{OS}	Input Offset Current	T_A = 25℃				5	50	nA
		T_A = full range					150	
CMRR	Common Mode Rejection Ratio	0V ≤ V_{CM} ≤ 4.0V			50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V ≤ V^+ ≤ 5V V_O = 1V, V_{CM} = 1V			50	60		dB
V_{CMR}	Input Common-Mode Voltage Range	For CMRR ≥ 50dB			0	-0.2		V
						4.2	4.0	
A_V	Large Signal Voltage Gain	R_L = 2 kΩ (Note 7)	T_A = 25℃		15	100		V/mV
			T_A = full range		10			
V_O	Output Swing	R_L = 2 kΩ to 2.5V	High level	T_A = 25℃	V^+ - 300	V^+ - 50		mV
				T_A = full range	V^+ - 400			
			Low level	T_A = 25℃		50	300	
				T_A = full range			400	
		R_L = 10 kΩ to 2.5V	High level	T_A = 25℃	V^+ - 100	V^+ - 10		
				T_A = full range	V^+ - 200			
			Low level	T_A = 25℃		10	180	
				T_A = full range			280	
I_O	Output Short Circuit Current	Sourcing, V_O = 0V			5	60		mA
		Sinking, V_O = 5V			10	90		
I_S	Supply Current	LMV321 Single amplifier				110	140	μA
		LMV358 Both amplifiers	T_A = 25℃			190	340	
			T_A = full range				600	
		LMV324 All four amplifiers	T_A = 25℃			340	680	
			T_A = full range				1100	
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353 (Note 8)				330		℃/W
		SOT25 (Note 8)				250		
		TSSOP-14L (Note 8)				100		
		MSOP-8L (Note 8)				203		
		SOP-8L (Note 8)				150		
		SOP-14L (Note 8)				83		

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Electrical Characteristics (Continued)

5V AC Electrical Characteristics Unless otherwise specified, all limits guaranteed for T_A = 25℃, V^+ = 5V, V^- = 0V, V_{CM} = 2.0V, VO = V^+/2 and R_L > 1 MΩ. **Boldface** limits apply at the temperature extremes.						
SR	Slew Rate	(Note 9)		1		V/µs
GBWP	Gain-Bandwidth Product	C_L = 200 pF		1		MHz
Φ_m	Phase Margin			60		Deg
G_m	Gain Margin			10		dB
e_n	Input-Referred Voltage Noise	f > 50 kHz		23		$\frac{nV}{\sqrt{H_Z}}$

Notes:
5. Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
6. All limits are guaranteed by testing or statistical analysis.
7. R_L is connected to V-. The output voltage is $0.5V \le V_O \le 4.5V$.
8. All numbers are typical, and apply for packages soldered directly onto a PC board in still air.
9. Connected as voltage follower with 3V step input. Number specified is the slower of the positive and negative slew rates.

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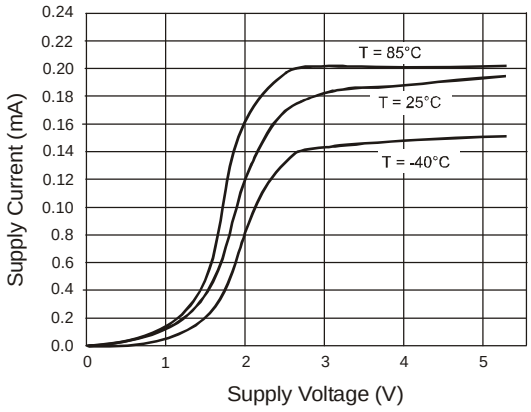
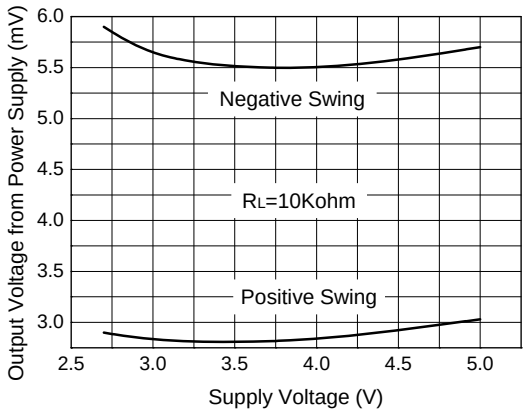
Typical Performance Characteristics

Unless otherwise specified, Vs=+5V, single supply, T_A=25°C

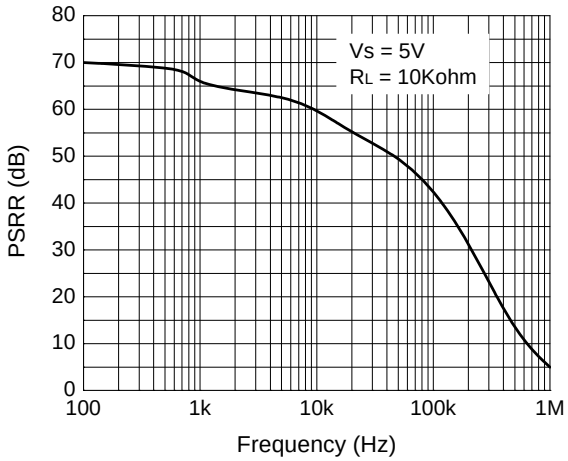
Supply Current vs. Supply Voltage



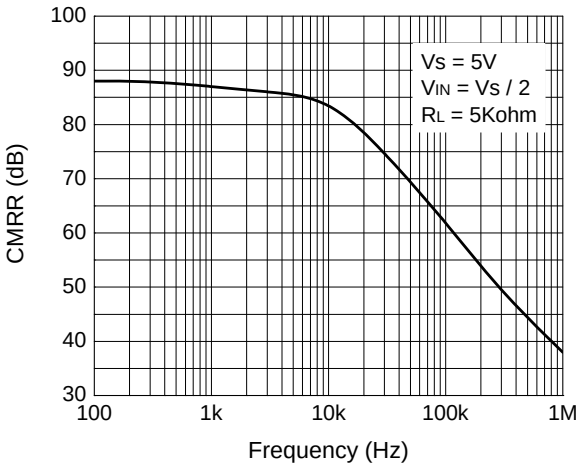
Output Voltage Swing vs. Supply Voltage



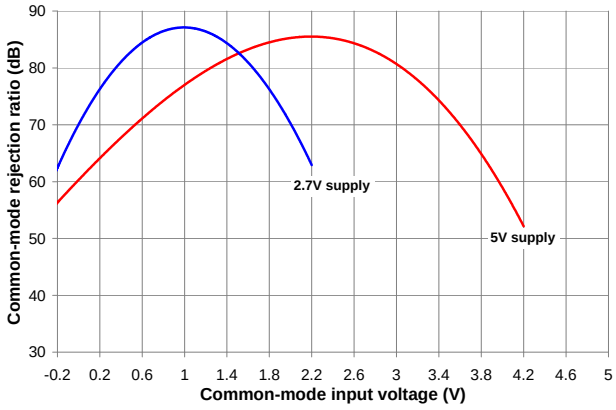
PSRR vs. Frequency



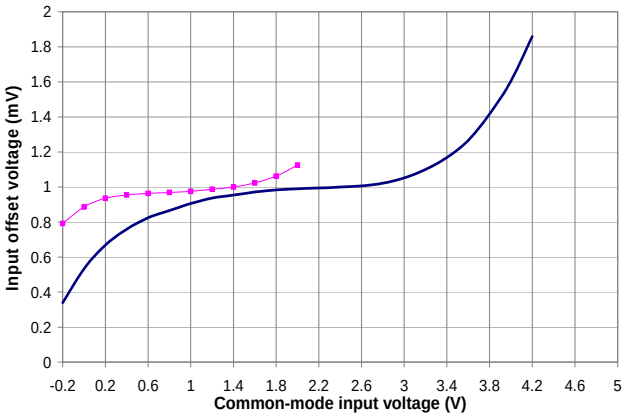
CMRR vs. Frequency



CMRR vs. Input Common Mode Voltage



ΔVos vs. CMR



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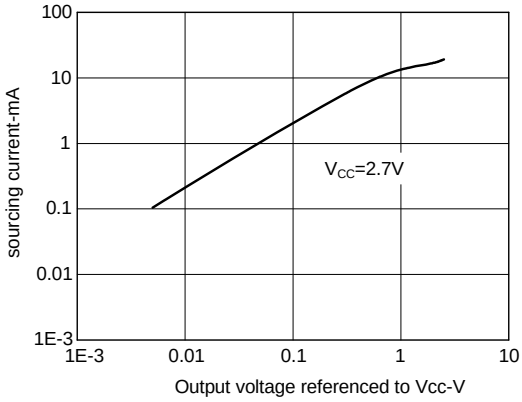
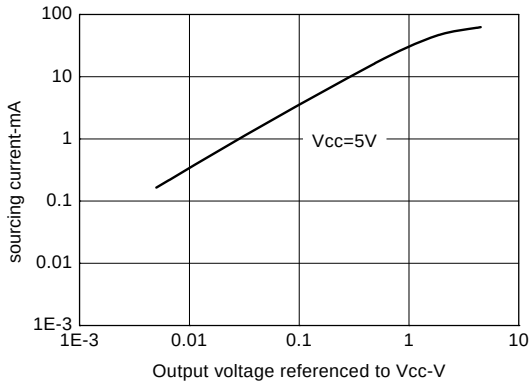
Typical Performance Characteristics (Continued)

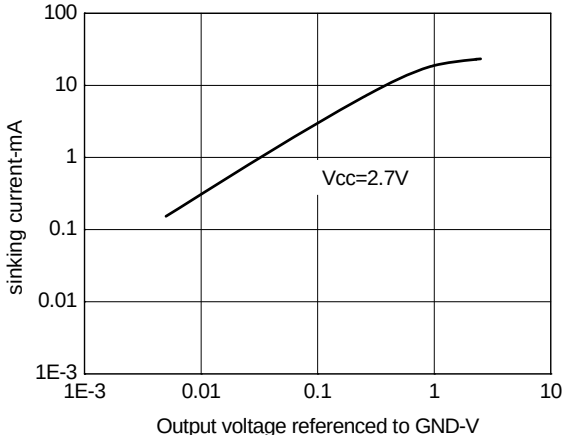
Sourcing Current vs. Output Voltage (2.7V)



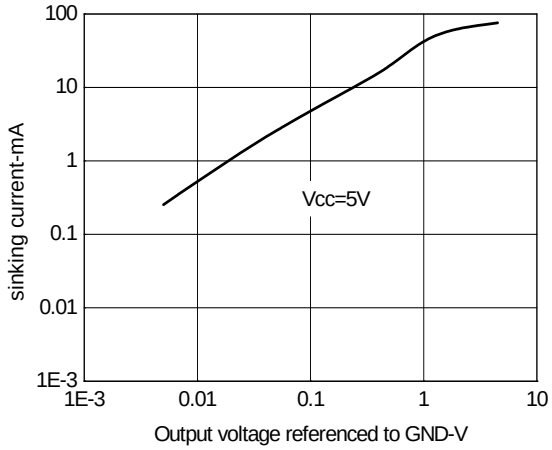
Sourcing Current vs. Output Voltage (5V)



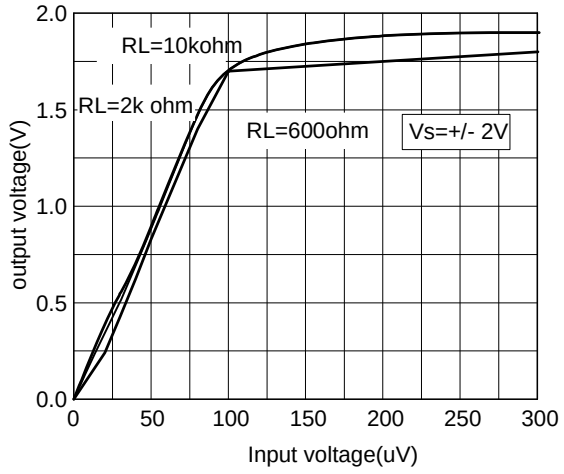
Sinking Current vs. Output Voltage (2.7V)



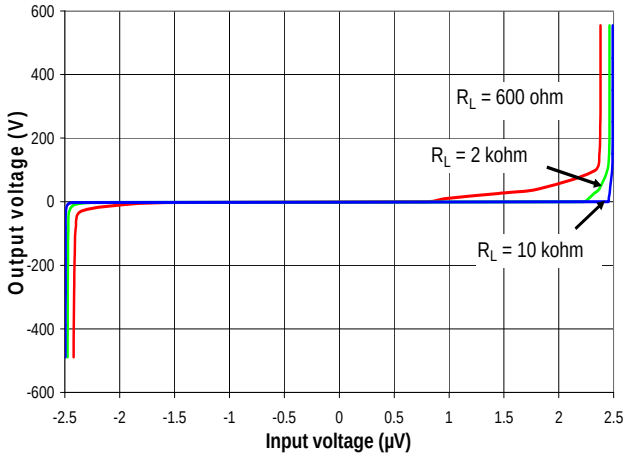
Sinking Current vs. Output Voltage (5V)



Input Voltage vs. Output Voltage



Output voltage vs. input voltage



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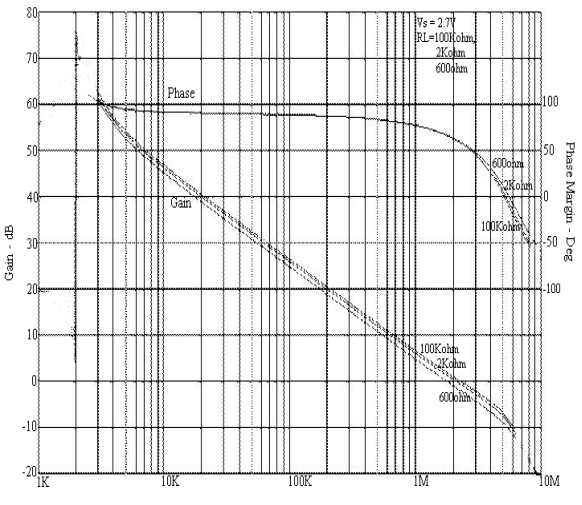
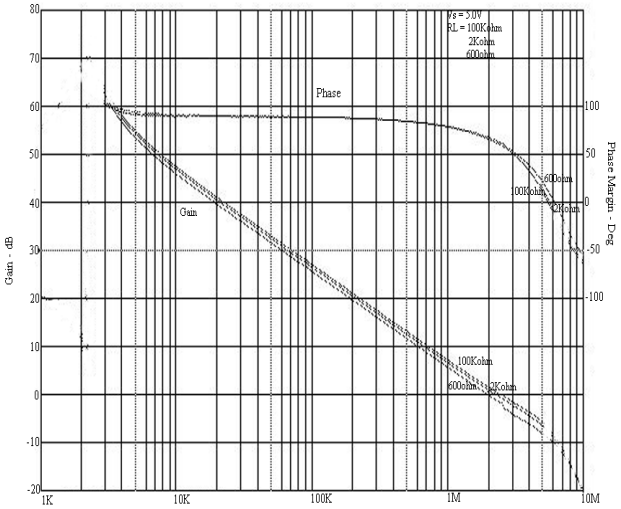
Typical Performance Characteristics (Continued)

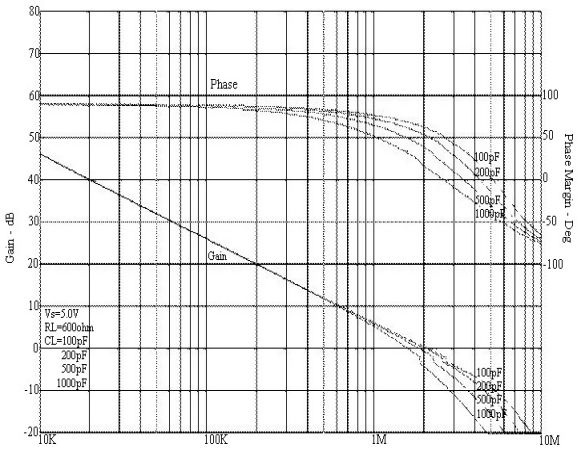
Frequency Response vs. Resistive Load (2.7V)



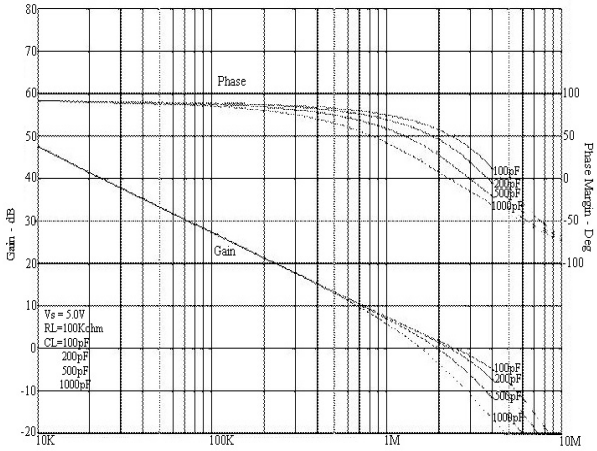
Frequency Response vs. Resistive Load (5V)



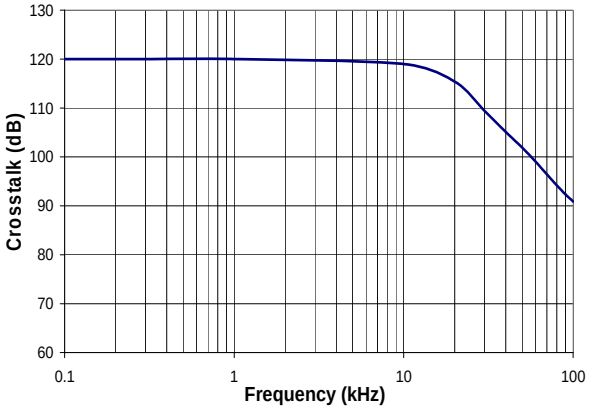
Frequency Response vs. Capacitive Load (2.7V)



Frequency Response vs. Capacitive Load (5V)



Crosstalk vs. Frequency



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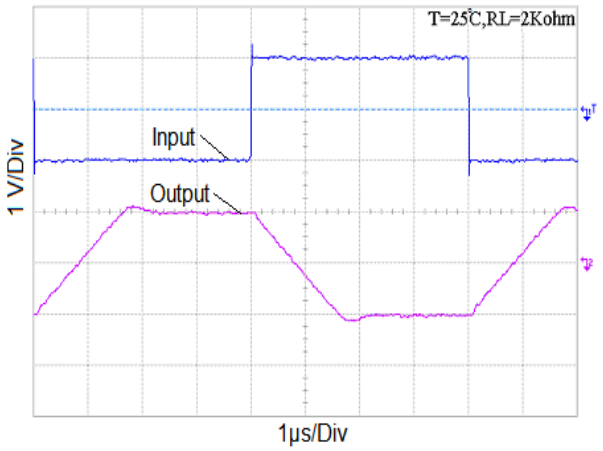
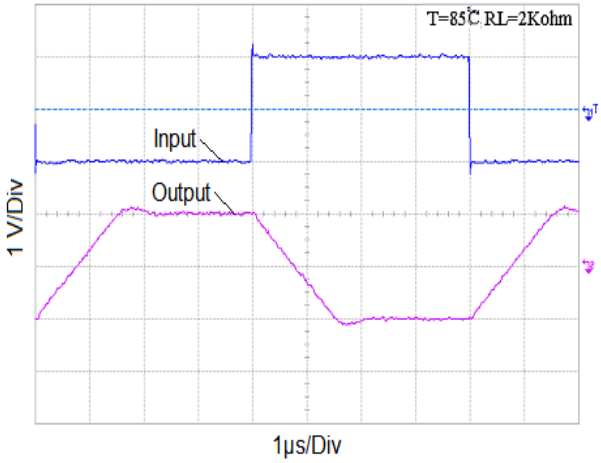
Typical Performance Characteristics (Continued)

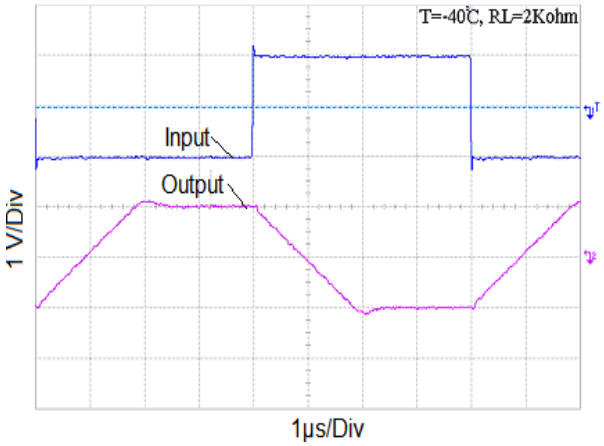
Inverting Large Signal Pulse Response



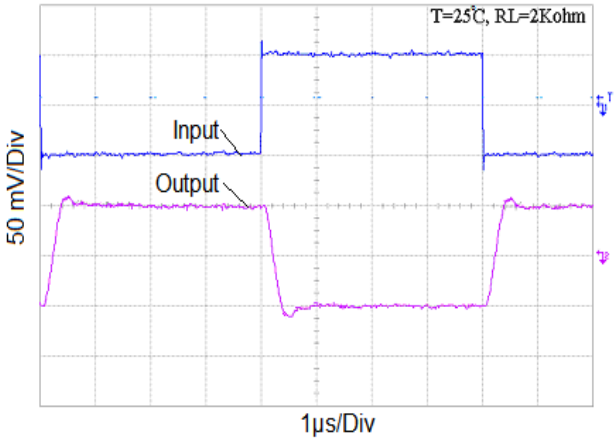
Inverting Large Signal Pulse Response



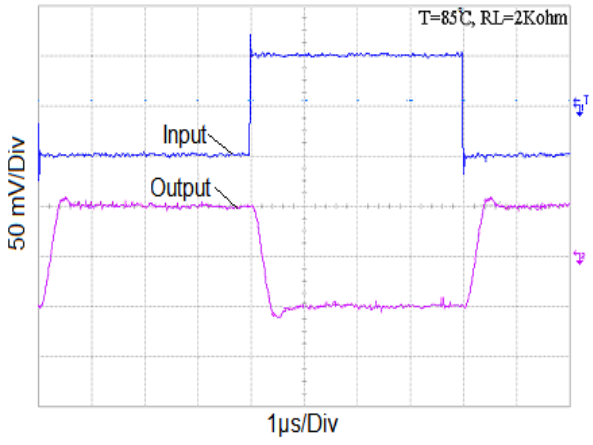
Inverting Large Signal Pulse Response



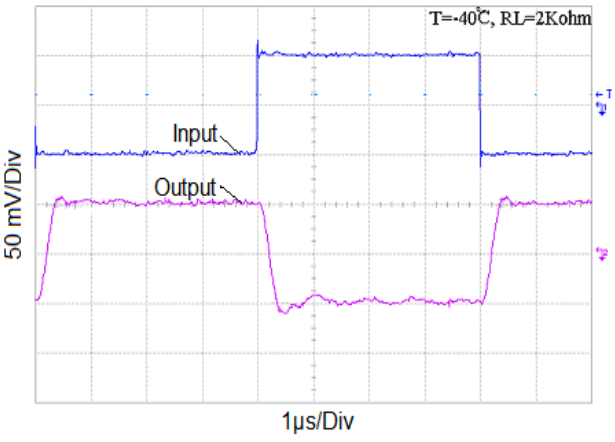
Inverting Small Signal Pulse Response



Inverting Small Signal Pulse Response



Inverting Small Signal Pulse Response



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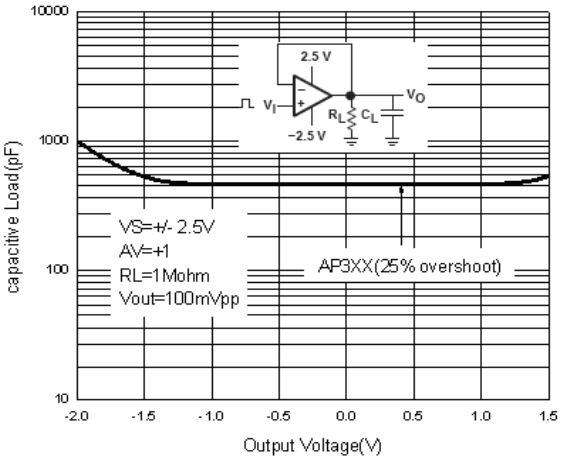
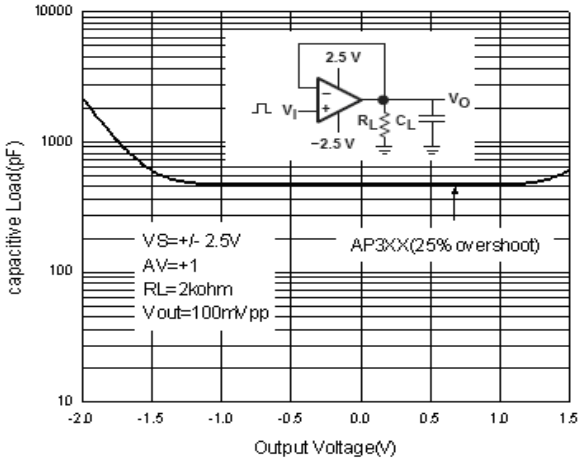
Typical Performance Characteristics (Continued)

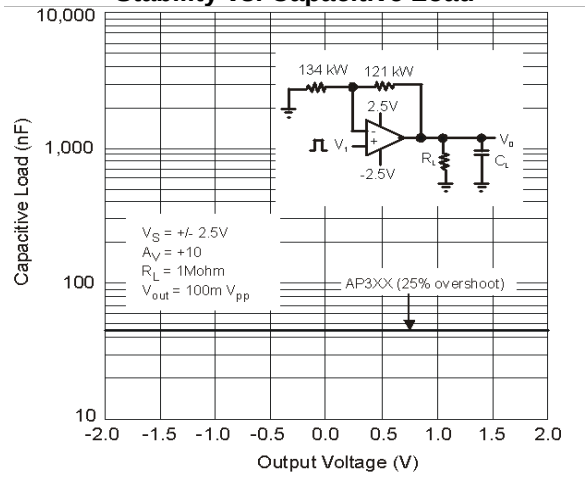
Stability vs. Capacitive Load



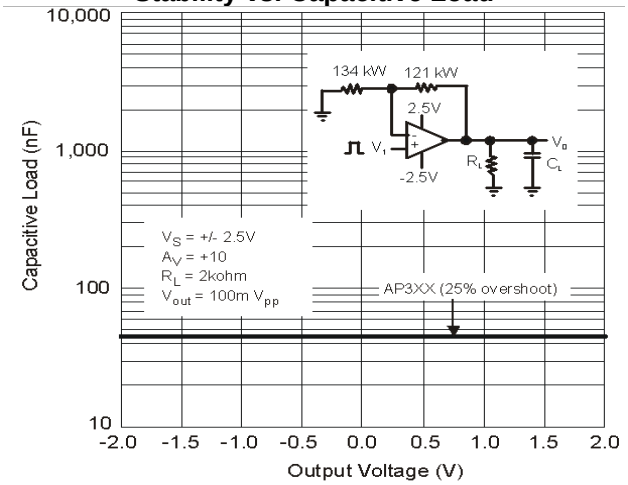
Stability vs. Capacitive Load



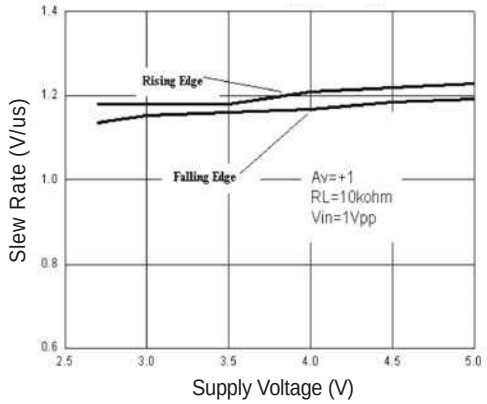
Stability vs. Capacitive Load



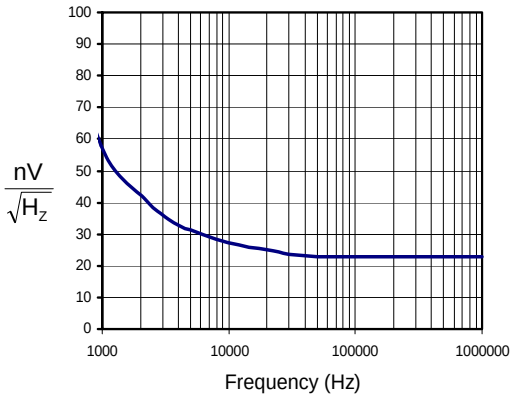
Stability vs. Capacitive Load



Slew Rate vs. Supply Voltage



Input Voltage Noise



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Ordering Information

LMV3 XX XX G - X

Part Number	Package	Green	Packing
21 : Single (Note 10)	W : SOT 25	G : Green	7/13 : Tape & Reel
24 : Quad (Note 11)	SE : SOT 353		
58 : Dual (Note 12)	B : SOP 14L		
	TS : TSSOP -14L		
	S : SOP 8L		
	M8 : MSOP -8L		

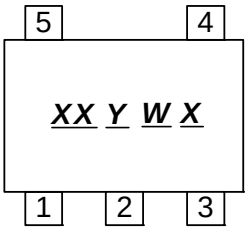
Device	Package Code	Packaging (Note 13)	7"/13" Tape and Reel	
			Quantity	Part Number Suffix
LMV321WG-7	W	SOT25	3000/Tape & Reel	-7
LMV321SEG-7	SE	SOT353	3000/Tape & Reel	-7
LMV324BG-13	B	SOP-14L	2500/Tape & Reel	-13
LMV324TSG-13	TS	TSSOP-14L	2500/Tape & Reel	-13
LMV358SG-13	S	SOP-8L	2500/Tape & Reel	-13
LMV358M8G-13	M8	MSOP-8L	2500/Tape & Reel	-13

Notes:
10. LMV321 is only available for SOT25 and SOT353.
11. LMV324 is only available for SOP-14L and TSSOP-14L.
12. LMV358 is only available for SOP-8L and MSOP-8L.
13. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information

SOT25 / SOT353

(Top View)



XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week;
z represents 52 and 53 week
X : A~Z : Green

Device	Package type	Identification Code
LMV321W	SOT25	BX
LMV321SE	SOT353	BY

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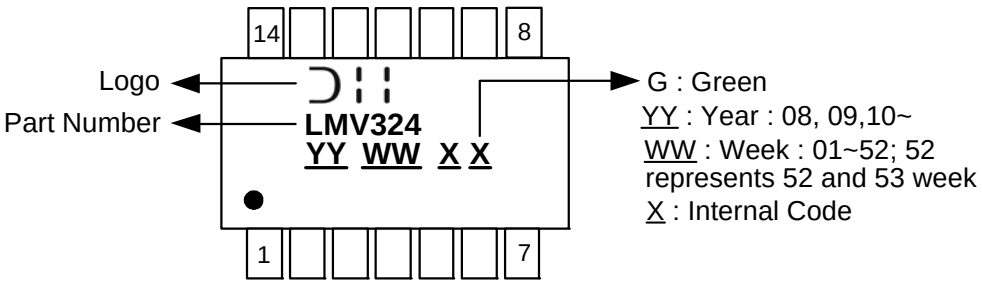
Marking Information (Continued)

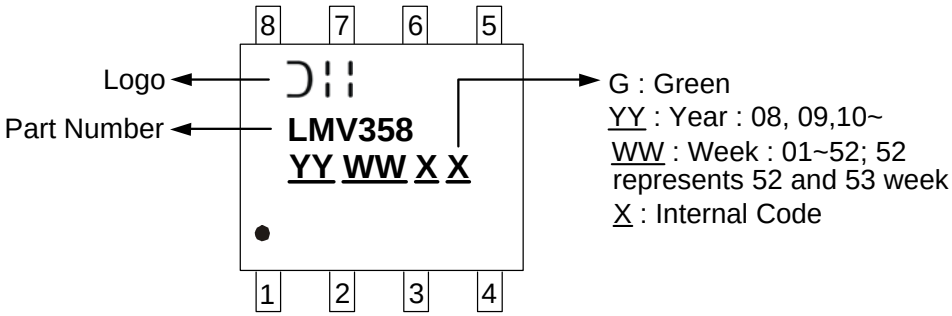
SOP-14L / TSSOP-14L

(Top View)



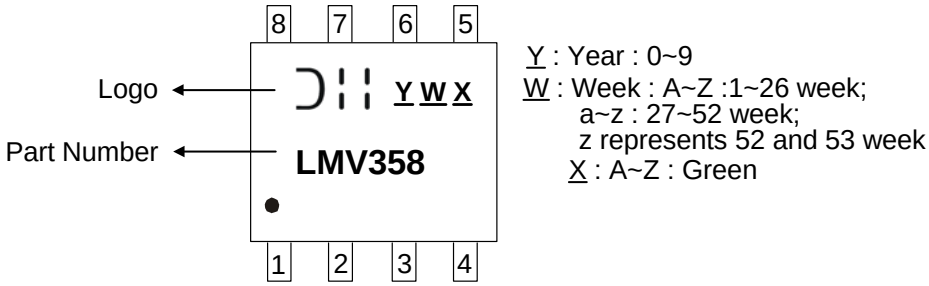
SOP-8L

(Top view)



MSOP-8L

(Top view)



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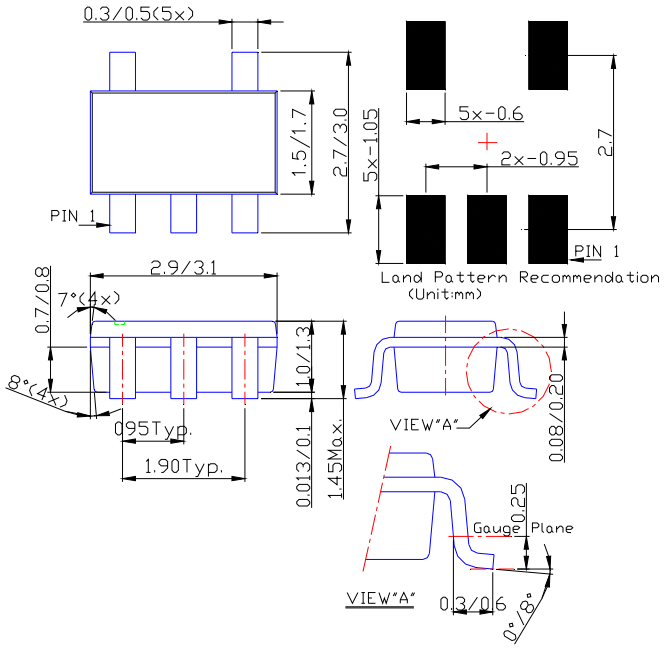
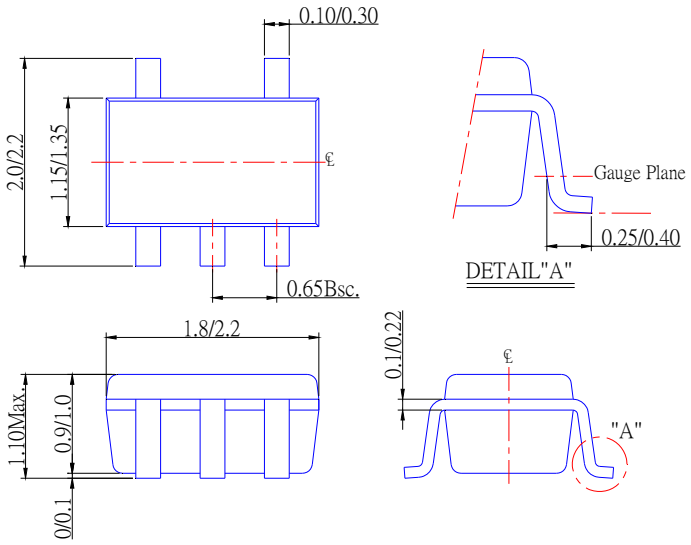
Package Information

Package Type: SOT25



Package Type: SOT353



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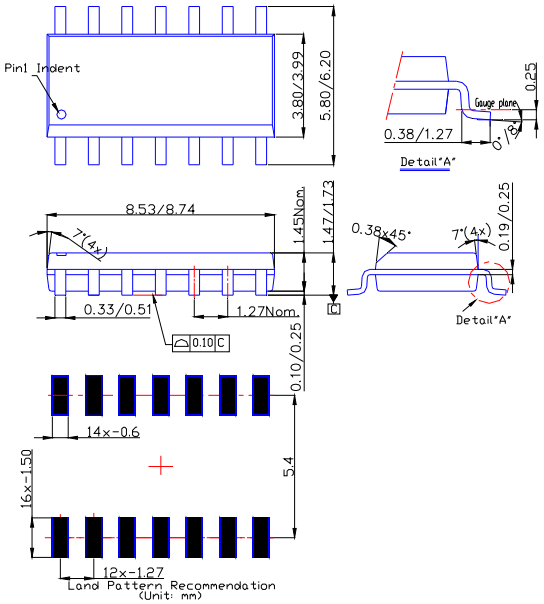
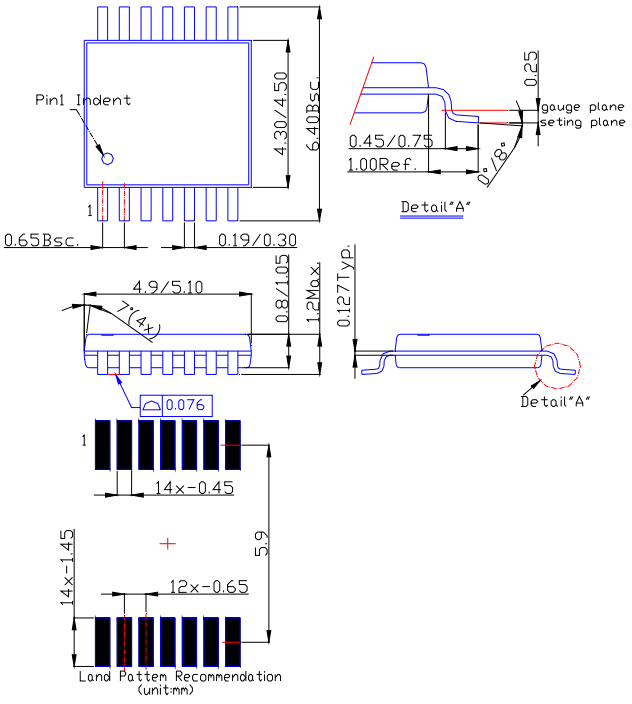
Package Information (Continued)

Package Type: SOP-14L



Package Type: TSSOP-14L



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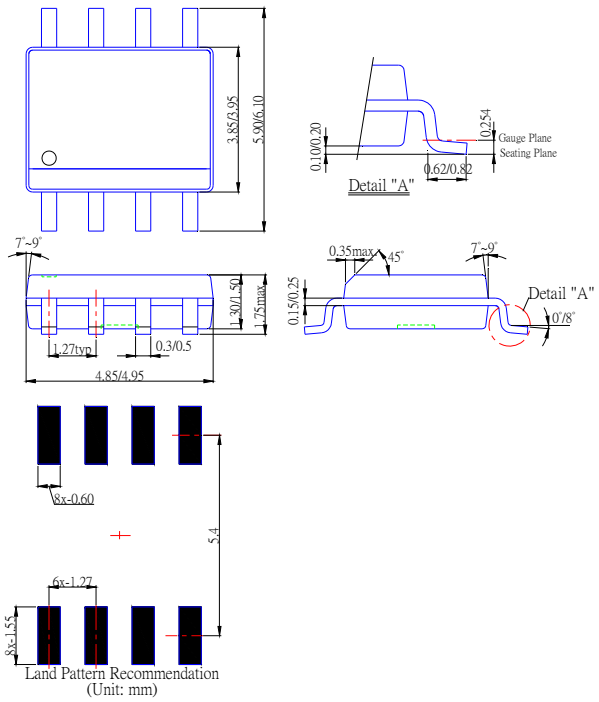
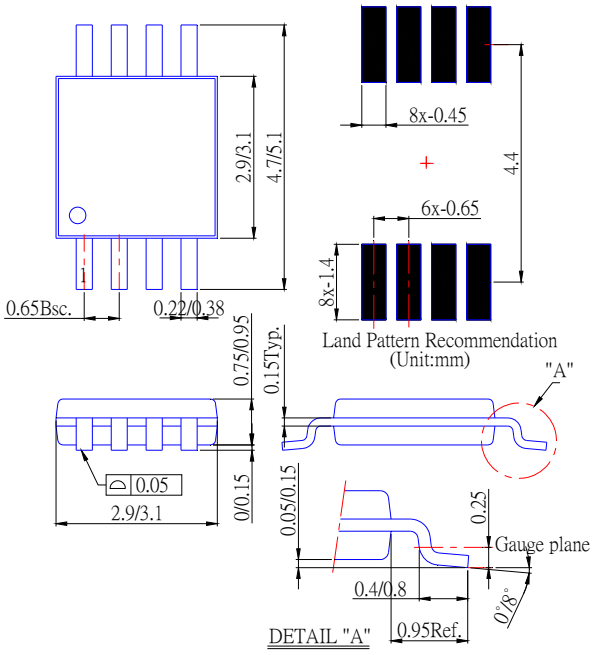
Package Information (Continued)

Package Type: SOP-8L



Package Type: MSOP-8L



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